NSN 5962-00-219-7734

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Between 0.735 inches and 0.830 inches

Body Width:

Between 0.260 inches and 0.293 inches

Body Height:

Between 0.140 inches and 0.180 inches

Maximum Power Dissipation Rating:

350.0 milliwatts

Operating Tempurature Range:

+0.0/+75.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

Digital data processing system, type an/gyk- (v)

Features Provided:

Monolithic and hermetically sealed and positive outputs and bipolar and programmable and programmed and w/decoded output and expandable and w/enable and w/open collector and w/buffered output

Inclosure Material:

Ceramic and glass

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

10 input

Terminal Surface Treatment:

Gold

Voltage Rating And Type Per Characteristic:

5.5 volts power source

Time Rating Per Chacteristic:

50.00 nanoseconds propagation delay time, low to high level output and 55.00 nanoseconds propagation delay time, high to low level output

Memory Device Type:

Rom

Memory Capacity:

Unknown

Precious Material And Location:

Terminals gold

Precious Material:

Gold

Test Data Document:

08241-1742-3328 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

16 printed circuit

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N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

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